NSN 5962-01-268-2907

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-268-2907 **Body Length:** Between 1.435 inches and 1.485 inches **Body Width:** Between 0.515 inches and 0.600 inches **Body Height:** Between 0.140 inches and 0.185 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Programmable and ultraviolet erasable and w/enable and high speed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 17 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.6 volts power source and 22.0 volts power source **Time Rating Per Chacteristic:** 200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level output **Memory Device Type: Eprom Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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Yes - demil/mli